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Should be replaced with:

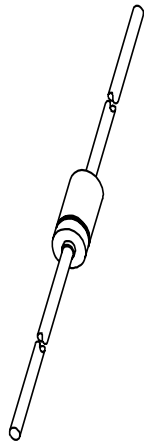
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via salesaddresses@nexperia.com). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DATA SHEET



1N4531; 1N4532 High-speed diodes

Product data sheet
Supersedes data of April 1996

1996 Sep 03

High-speed diodes

1N4531; 1N4532

FEATURES

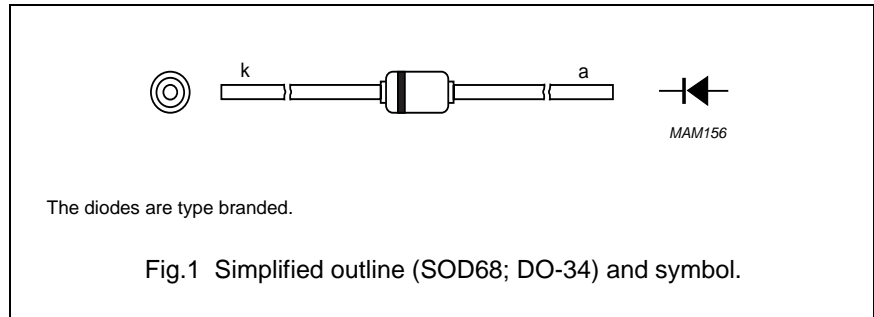
- Hermetically sealed leaded glass SOD68 (DO-34) package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 75 V
- Repetitive peak forward current: max. 450 mA.

APPLICATIONS

- High-speed switching
- Protection diodes in reed relays.

DESCRIPTION

The 1N4531, 1N4532 are high-speed switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD68 (DO-34) packages.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage		–	75	V
V_R	continuous reverse voltage		–	75	V
I_F	continuous forward current	see Fig.2	–	200	mA
I_{FRM}	repetitive peak forward current		–	450	mA
I_{FSM}	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 1\ \text{ms}$ $t = 1\ \text{s}$	–	4 1 0.5	A A A
P_{tot}	total power dissipation	$T_{amb} = 25\text{ °C}$	–	500	mW
T_{stg}	storage temperature		–65	+200	°C
T_j	junction temperature		–	200	°C

High-speed diodes

1N4531; 1N4532

ELECTRICAL CHARACTERISTICST_j = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	I _F = 10 mA; see Fig.3	–	1000	mV
I _R	reverse current	see Fig.5			
	IN4531	V _R = 20 V	–	25	nA
		V _R = 20 V; T _j = 150 °C	–	50	μA
	IN4532	V _R = 50 V	–	100	nA
		V _R = 50 V; T _j = 150 °C	–	100	μA
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6			
	IN4531		–	4	pF
	IN4532		–	2	pF
t _{rr}	reverse recovery time	when switched from I _F = 10 mA to I _R = 60 mA; R _L = 100 Ω; measured at I _R = 1 mA; see Fig.7			
	IN4531		–	4	ns
	IN4532		–	2	ns
	reverse recovery time	when switched from I _F = 10 mA to I _R = 10 mA; R _L = 100 Ω; measured at I _R = 1 mA; see Fig.7			
	IN4532		–	4	ns
V _{fr}	forward recovery voltage	when switched from I _F = 100 mA; t _r ≤ 30 ns; see Fig.8	–	3	V

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length 5 mm	120	K/W
R _{th j-a}	thermal resistance from junction to ambient	lead length 5 mm; note 1	350	K/W

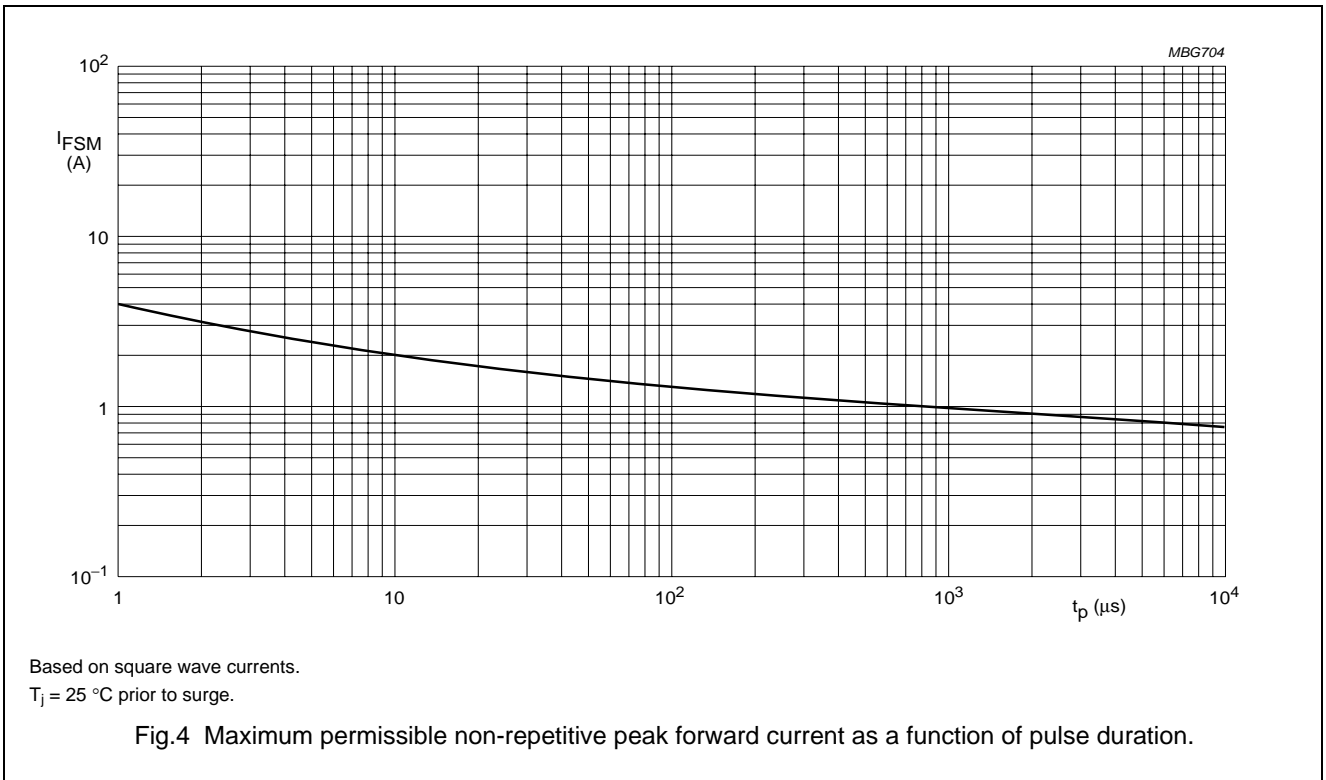
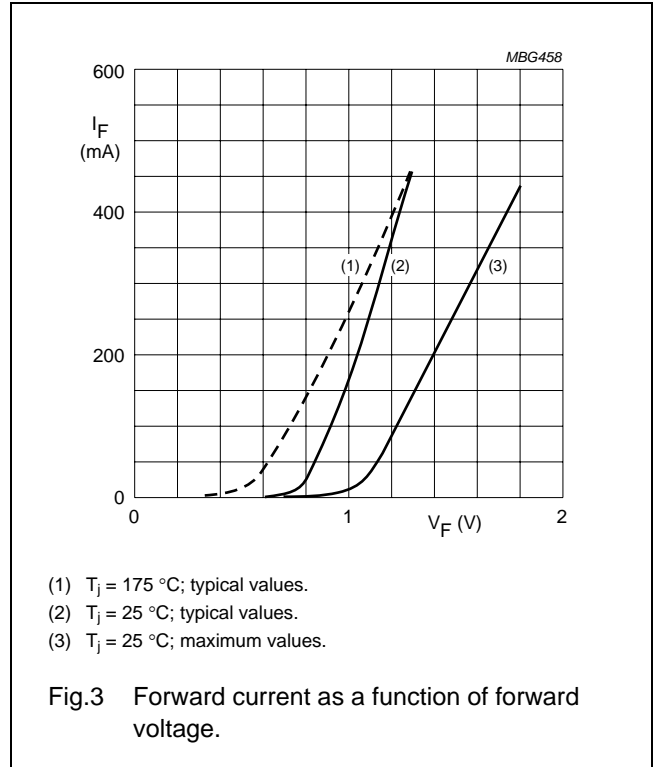
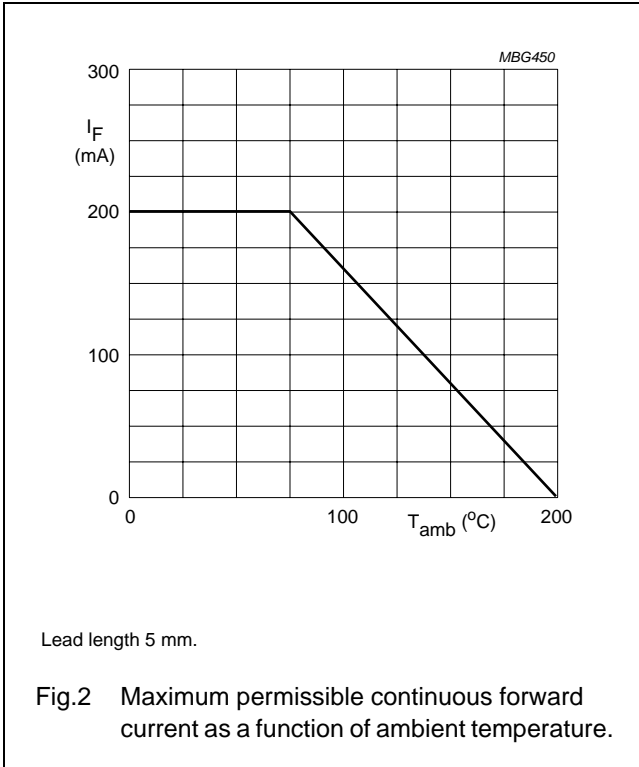
Note

1. Device mounted on a printed circuit-board without metallization pad.

High-speed diodes

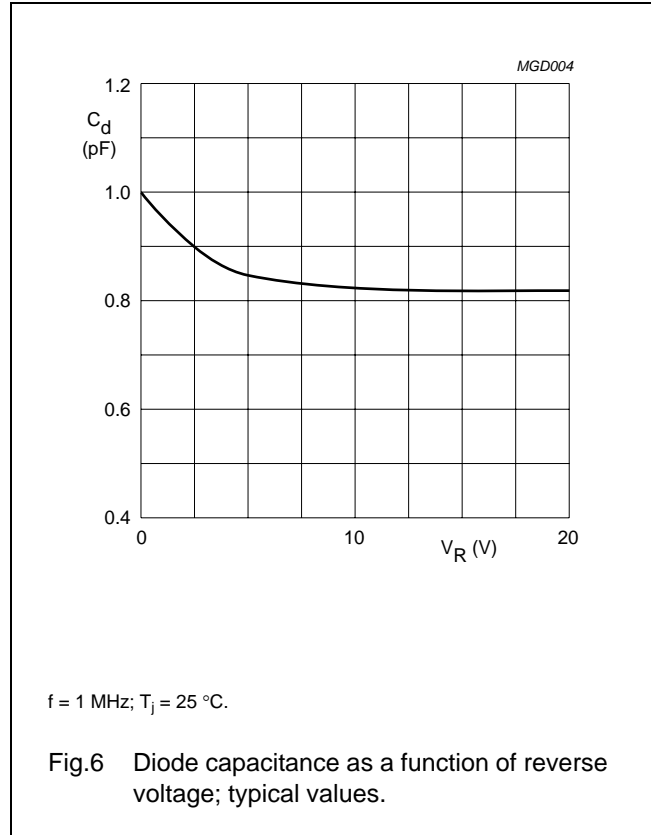
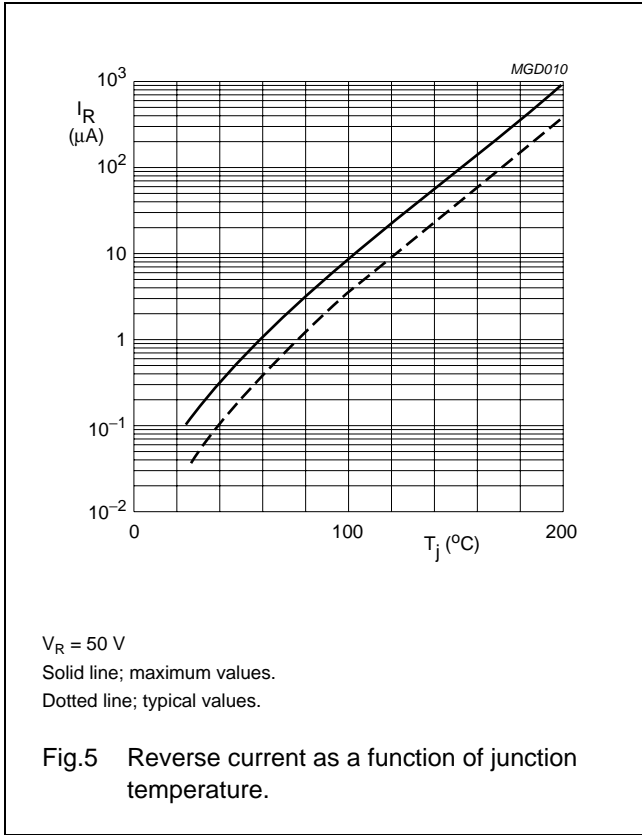
1N4531; 1N4532

GRAPHICAL DATA



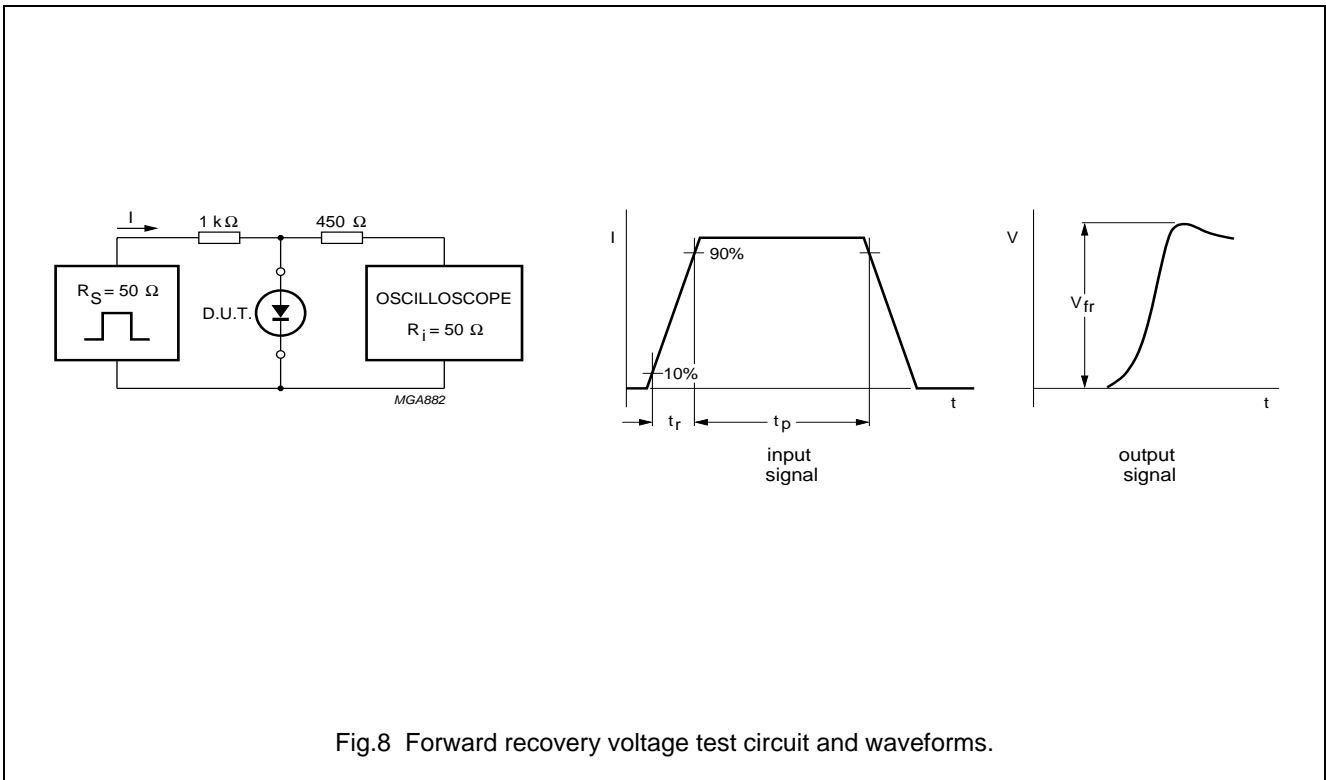
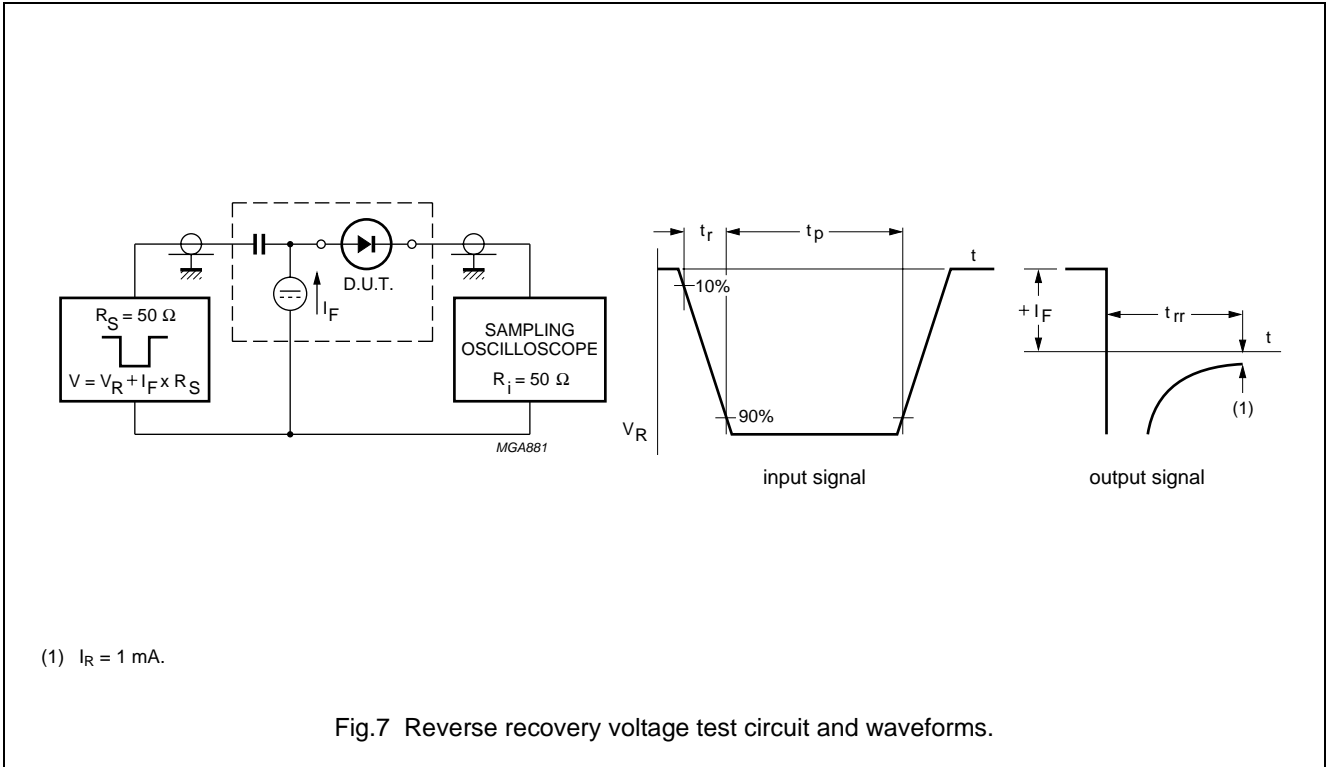
High-speed diodes

1N4531; 1N4532



High-speed diodes

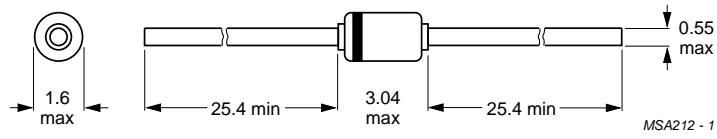
1N4531; 1N4532



High-speed diodes

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PACKAGE OUTLINE



Dimensions in mm.

Fig.9 SOD68 (DO-34).

High-speed diodes

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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NXP Semiconductors

Customer notification

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Contact information

For additional information please visit: **<http://www.nxp.com>**

For sales offices addresses send e-mail to: **salesaddresses@nxp.com**

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